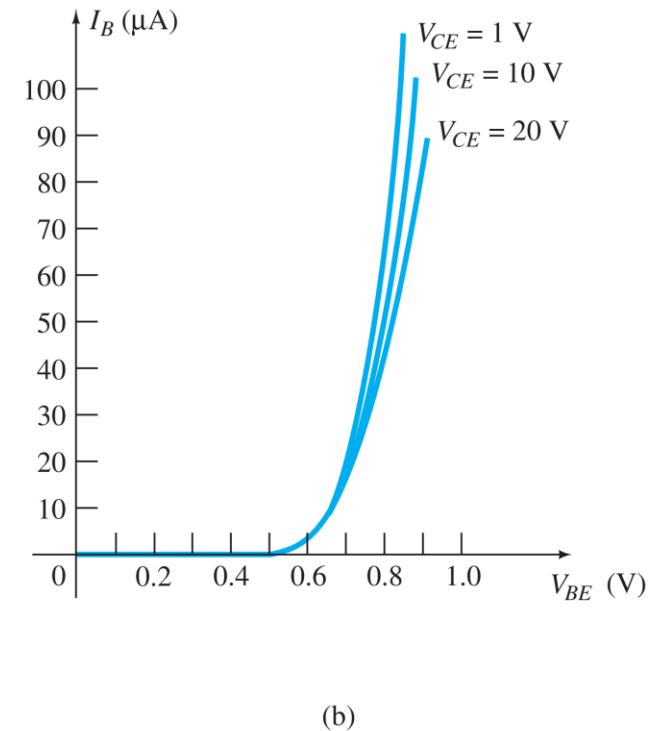
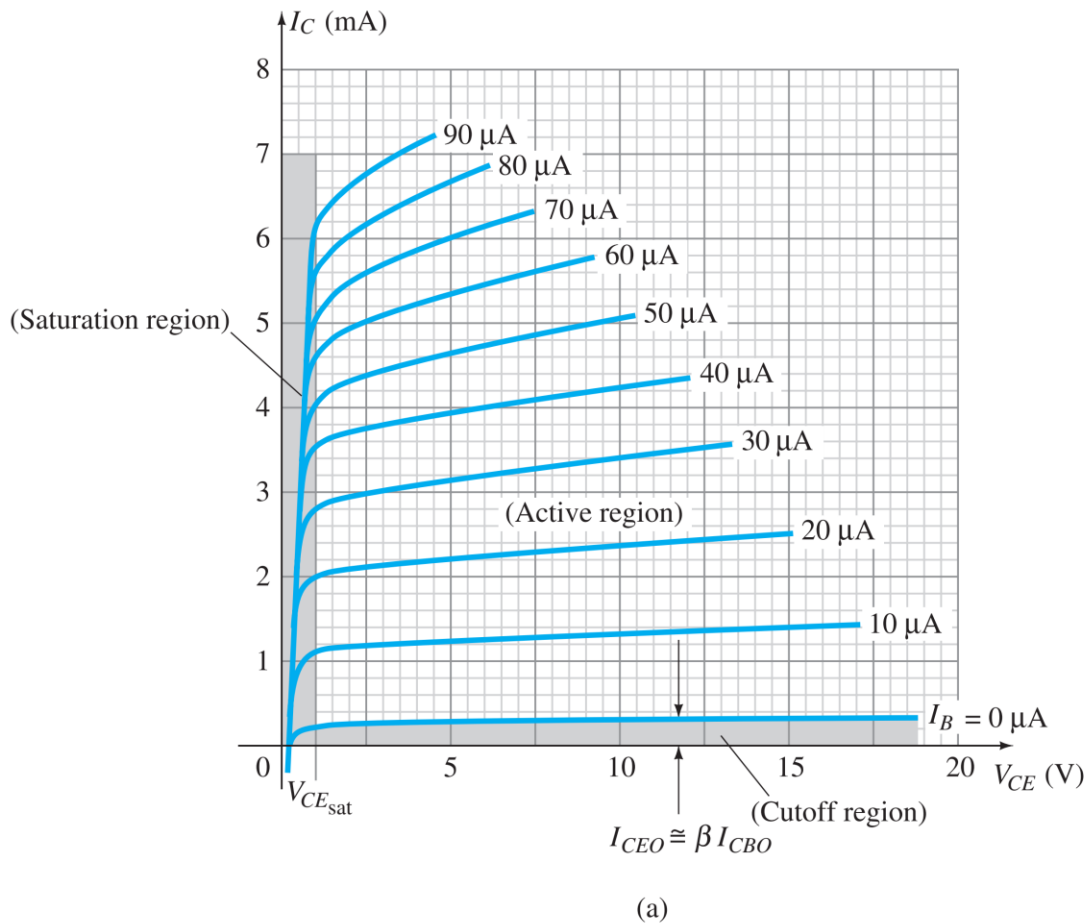


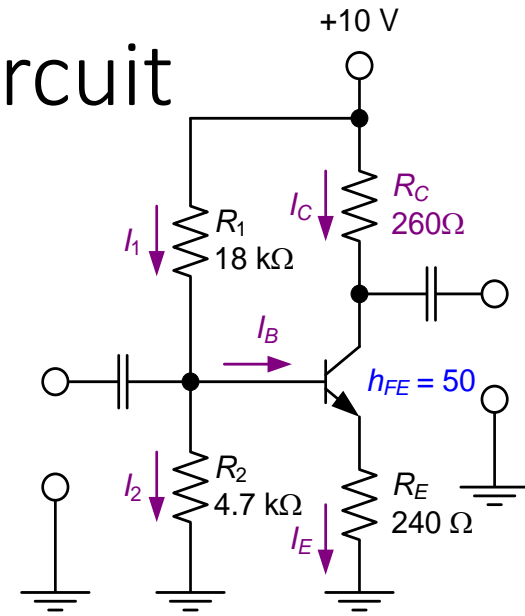
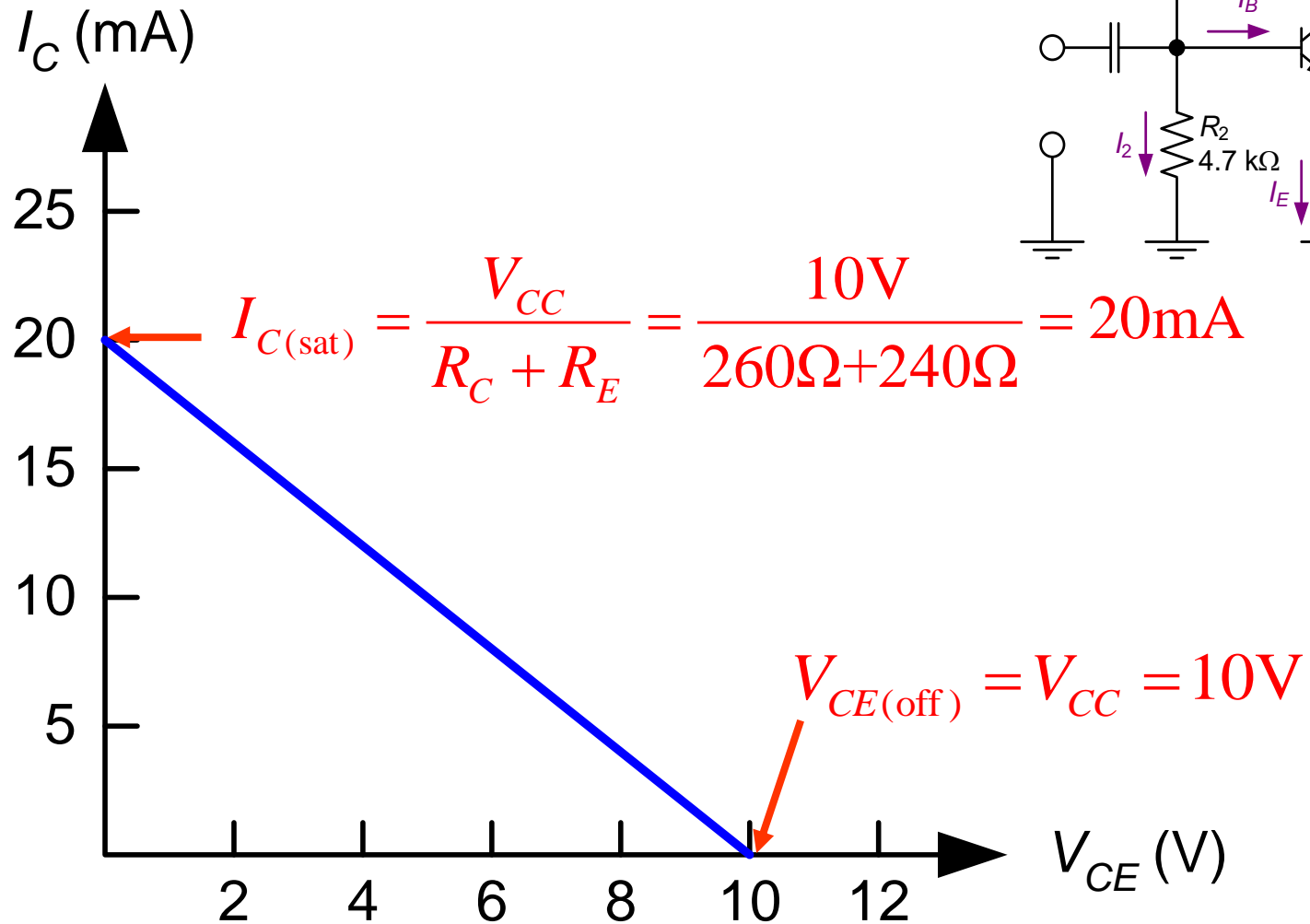
Supplementation

Week 8

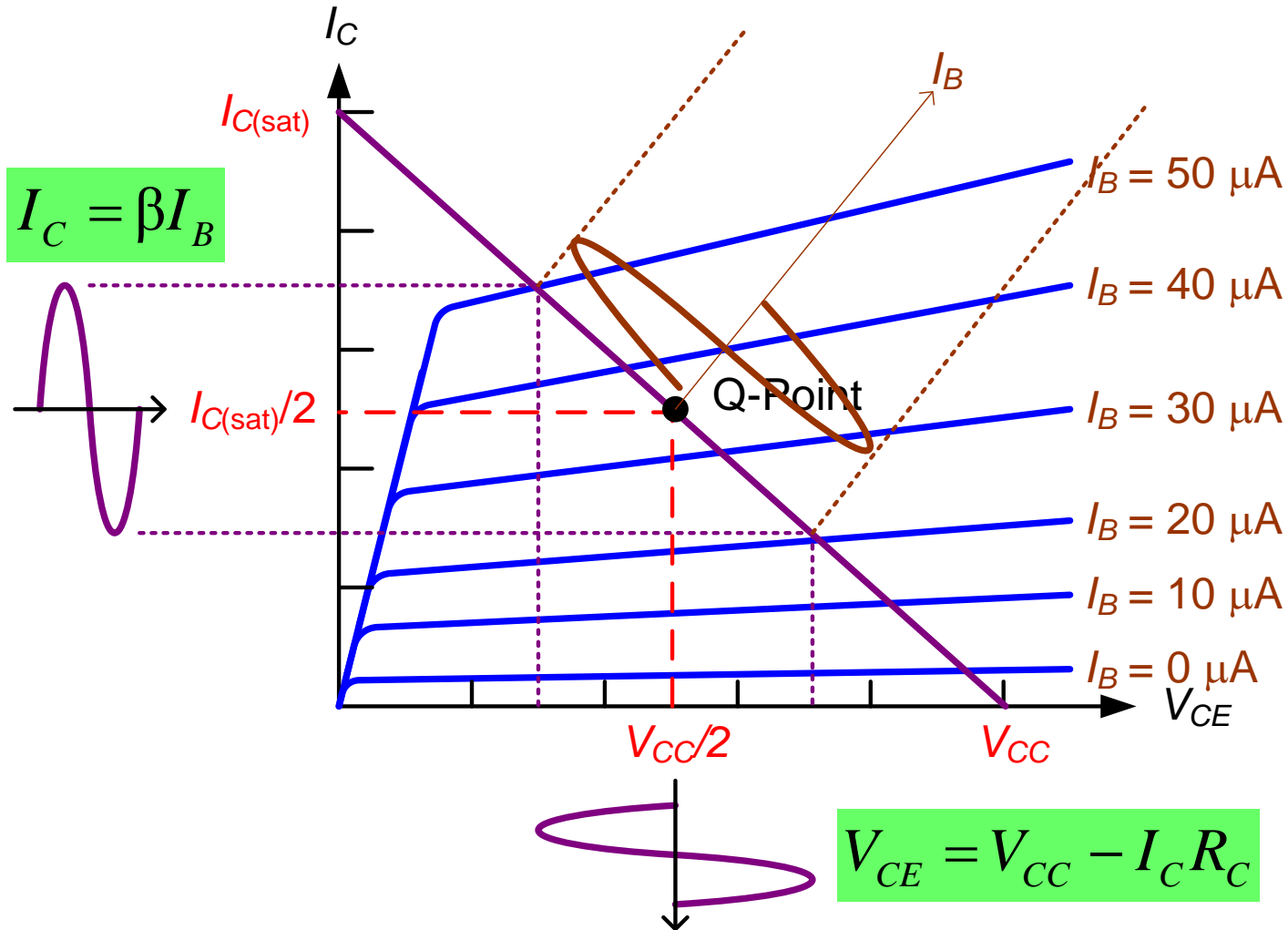
Operating regions



Load line for voltage divider bias circuit



Q-point with amplifier operation, Where?



Switching Circuit Calculations

Saturation current:

$$I_{Csat} = \frac{V_{CC}}{R_C}$$

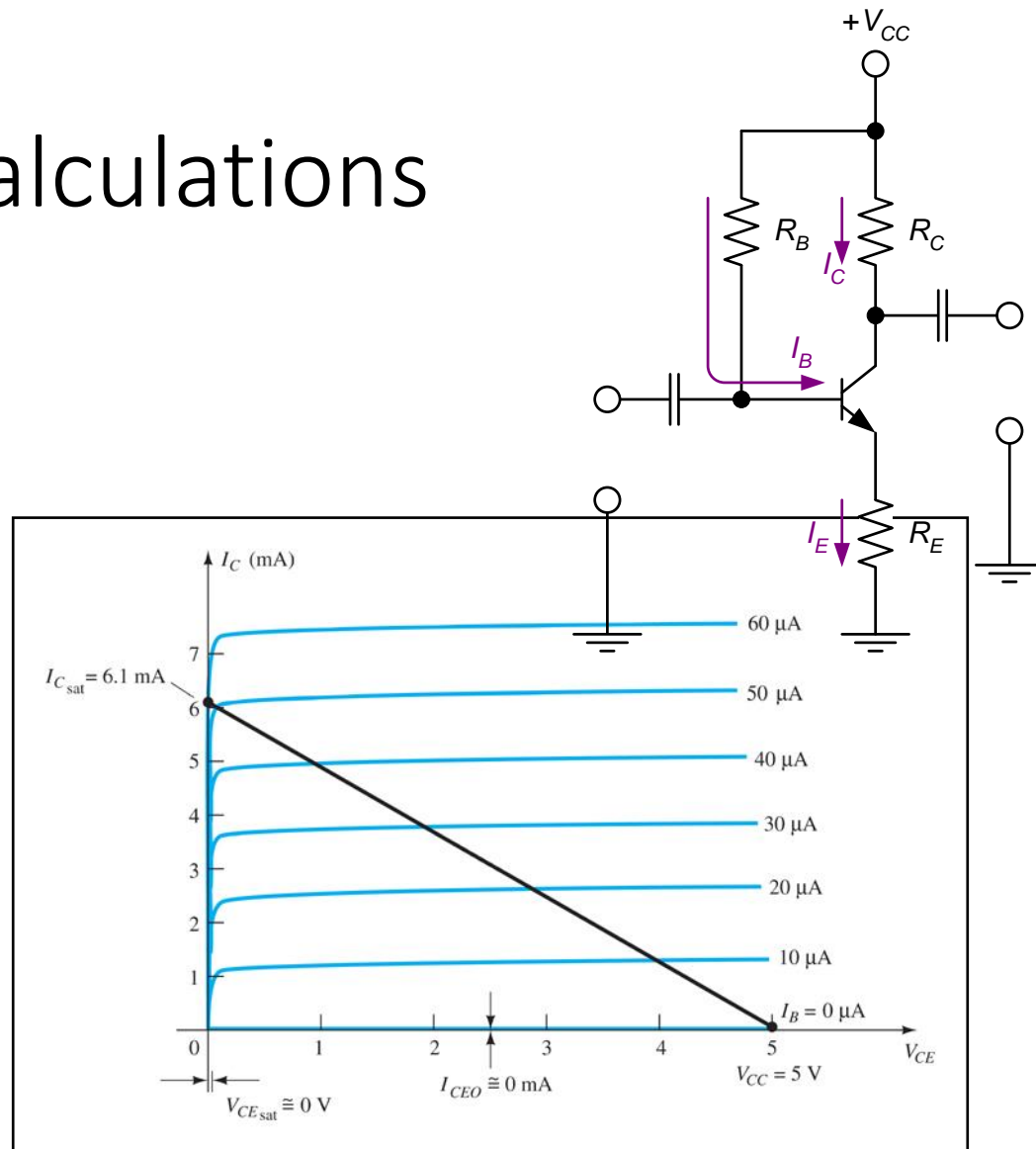
To ensure saturation:

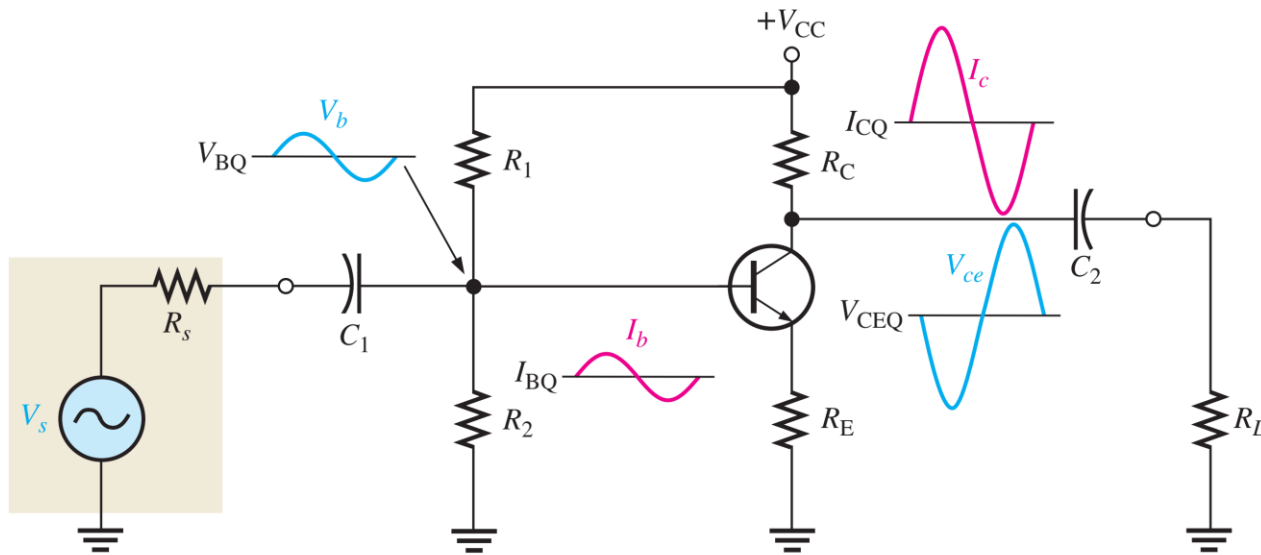
$$I_B > \frac{I_{Csat}}{\beta_{dc}}$$

Emitter-collector
resistance at
saturation and cutoff:

$$R_{sat} = \frac{V_{CEsat}}{I_{Csat}}$$

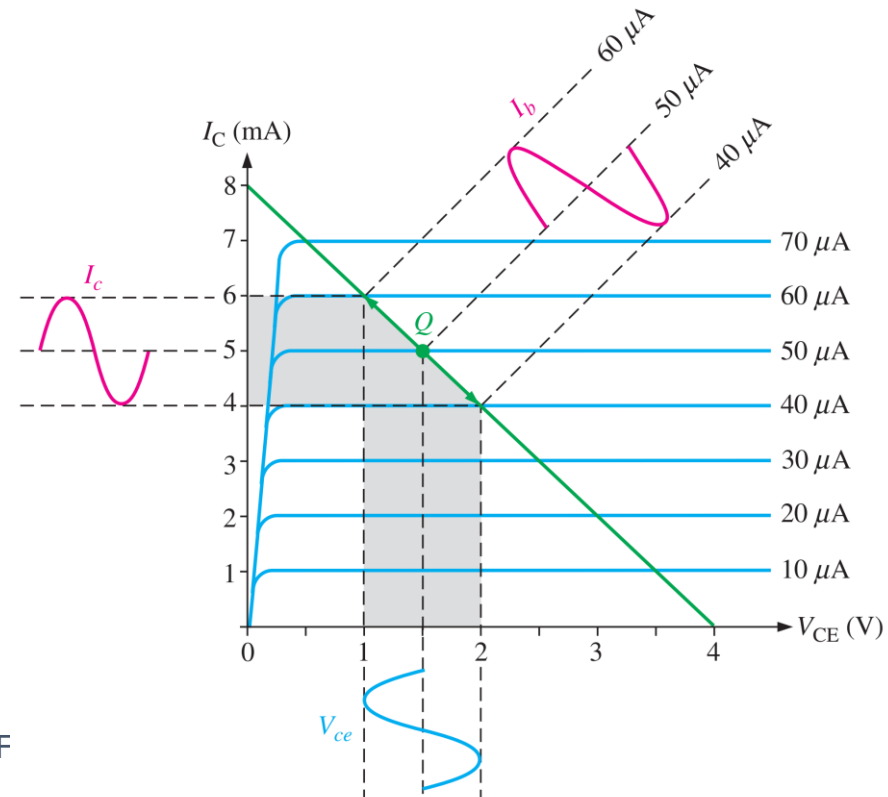
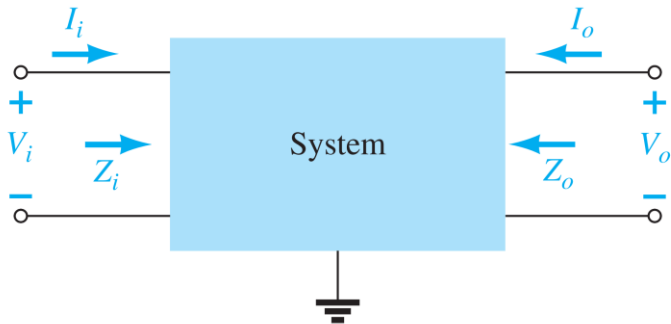
$$R_{cutoff} = \frac{V_{CC}}{I_{CEO}}$$

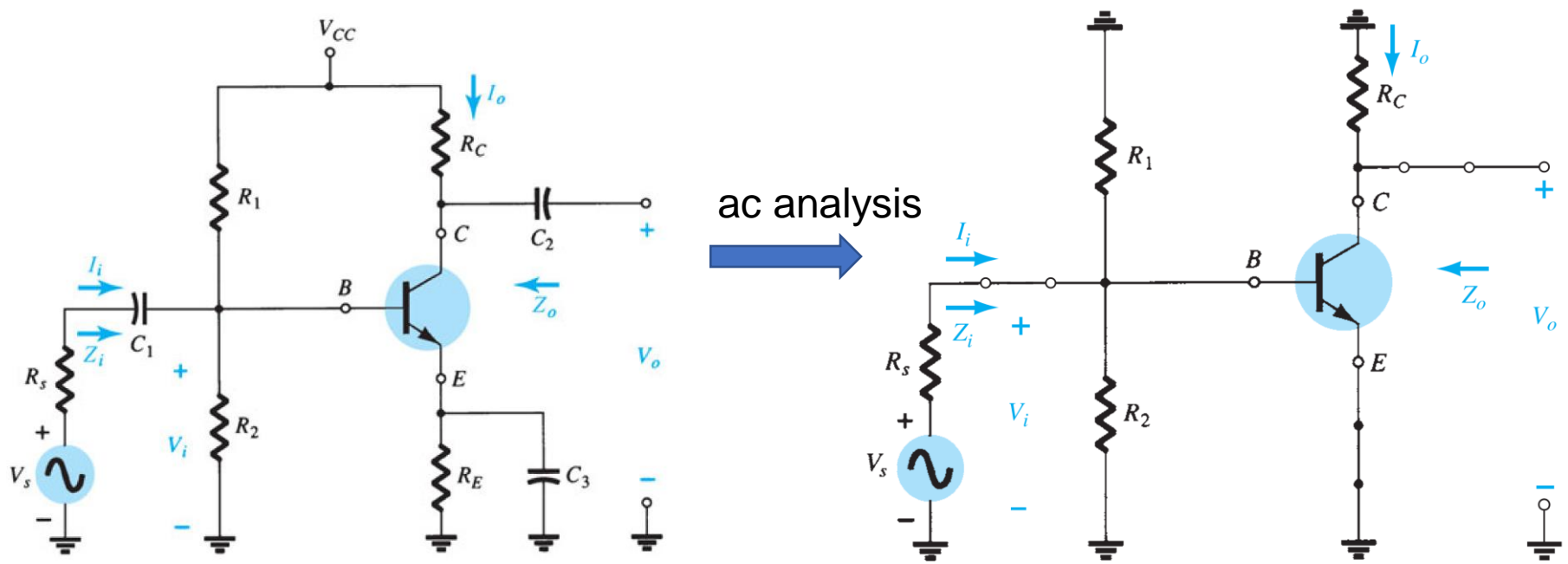




The important circuit parameters:

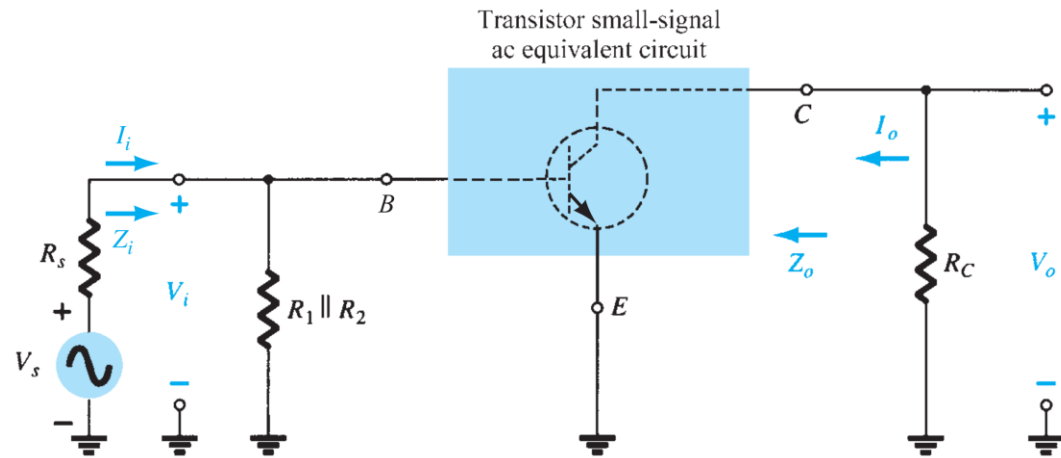
1. $Z_i = V_i/I_i$ input impedance
2. $Z_o = V_o/I_o$ output impedance
3. $A_v = V_o/V_i$ voltage gain
4. $A_i = I_o/I_i$ current gain



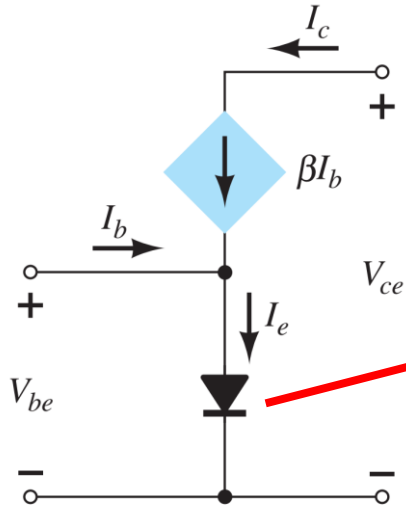


In summary, therefore, the ac equivalent of a transistor network is obtained by:

1. Setting all dc sources to zero and replacing them by a short-circuit equivalent
2. Replacing all capacitors by a short-circuit equivalent
3. Removing all elements bypassed by the short-circuit equivalents introduced by steps 1 and 2
4. Redrawing the network in a more convenient and logical form



The r_e Transistor Model

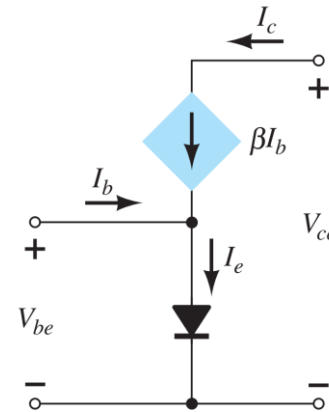
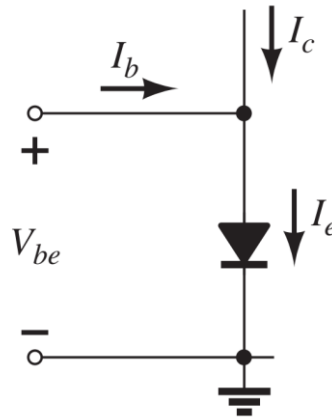
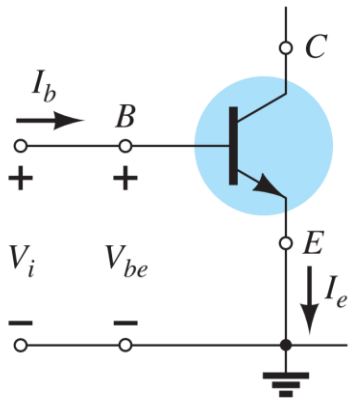


ac resistance of the diode

$$r_e = \frac{dI_D}{dV} = \frac{d}{dV} [I_S (e^{V/\eta kT} - 1)]$$

for Si and $T = 25^\circ\text{C}$, $r_e = \frac{26\text{mV}}{I_e}$ For $I_D = I_e \gg I_S$
(a few ohms)

Common-Emitter Configuration



The diode r_e model can be replaced by the resistor r_e .

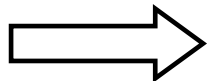
$$r_e = \frac{26 \text{ mV}}{I_e}$$

Current through diode:

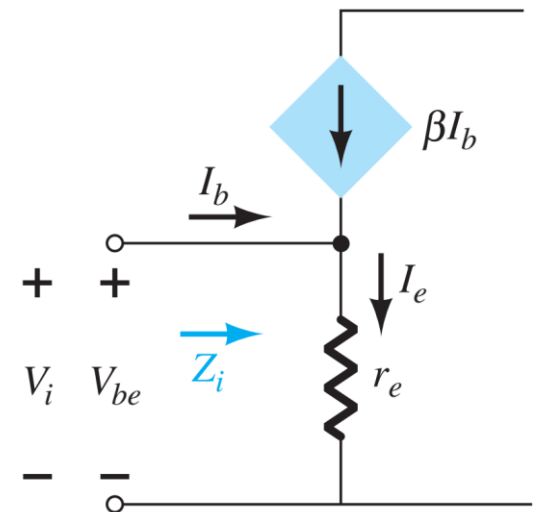
$$I_e = I_c + I_b = \beta I_b + I_b = (\beta + 1)I_b \cong \beta I_b$$

(generally $\beta \gg 1$)

Input impedance: $Z_i = \frac{V_i}{I_i} = \frac{V_{be}}{I_b} = \frac{I_e r_e}{I_b} \cong \frac{\beta I_b r_e}{I_b}$



$$Z_i \cong \beta r_e$$



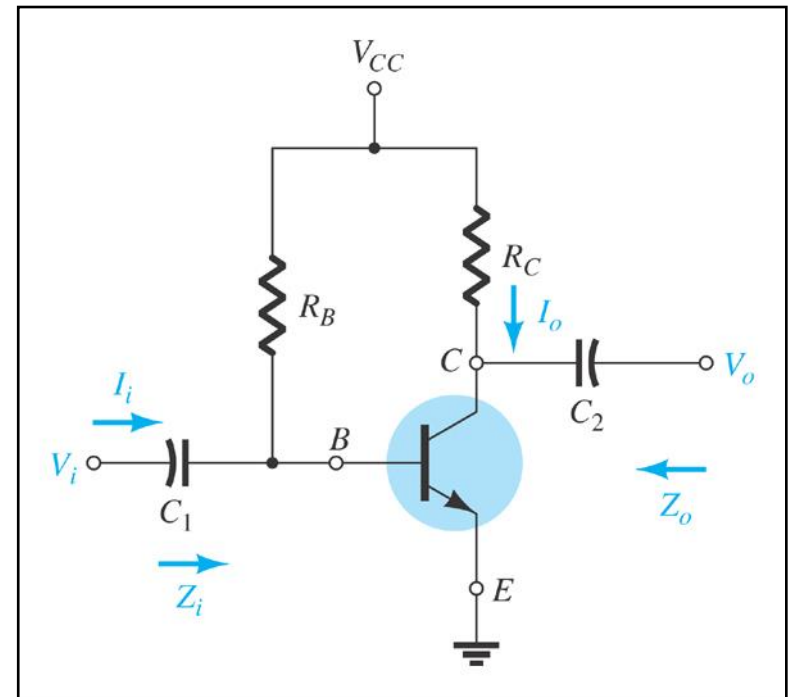
Common-Emitter Fixed-Bias Configuration

The input is applied to the base
The output is taken from the collector

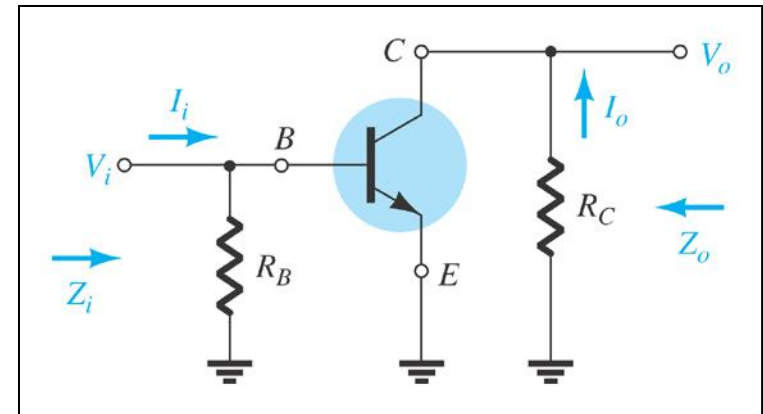
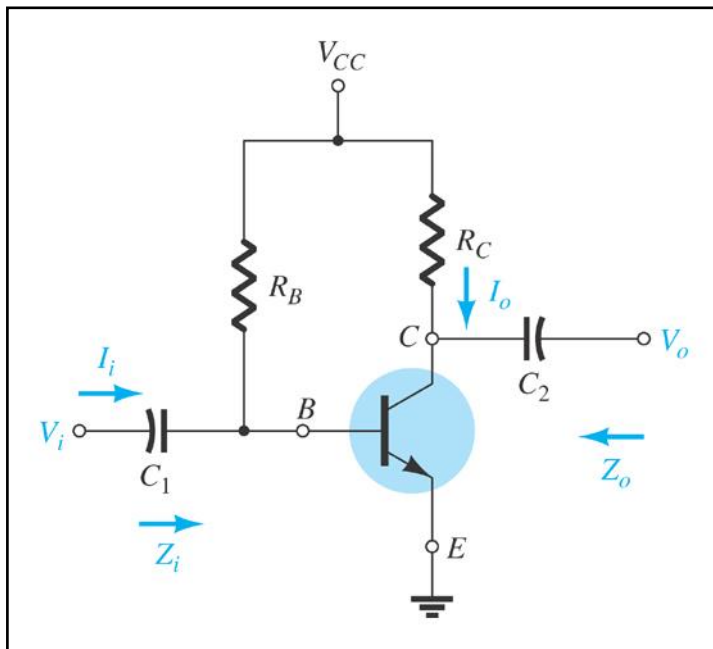
High input impedance
Low output impedance

High voltage and current gain

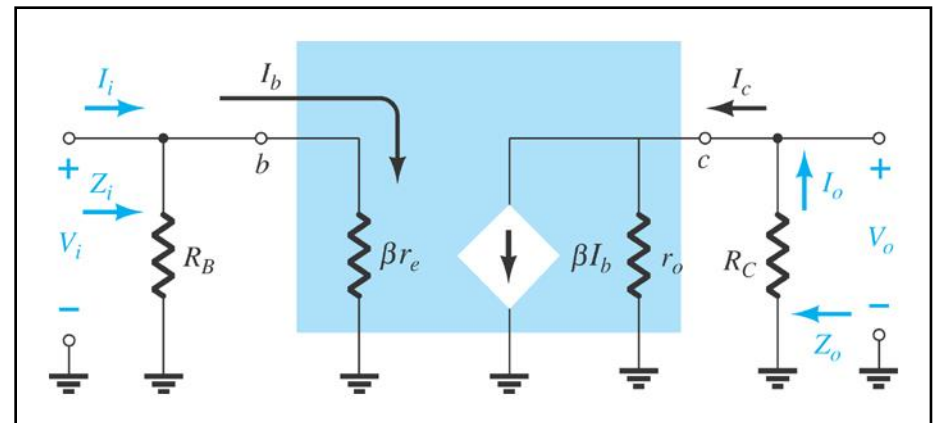
Phase shift between input and output is 180°



Common-Emitter Fixed-Bias Configuration



AC equivalent



r_e model

Common-Emitter Fixed-Bias Calculations

Input impedance:

$$Z_i = R_B \parallel \beta |e$$

$$Z_i \cong \beta r_e \Big|_{R_E \geq 10 \beta r_e}$$

Output impedance:

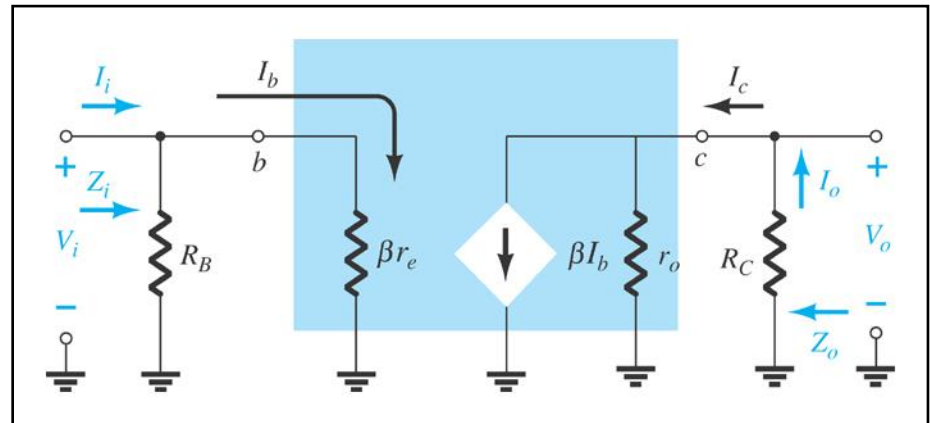
$$Z_o = R_C \parallel r_o$$

$$Z_o \cong R_C \Big|_{r_o \geq 10 R_C}$$

Voltage gain:

$$A_v = \frac{V_o}{V_i} = -\frac{(R_C \parallel r_o)}{r_e}$$

$$A_v \cong -\frac{R_C}{r_e} \Big|_{r_o \geq 10 R_C}$$



Current gain:

$$A_i = \frac{I_o}{I_i} = \frac{\beta R_B r_o}{(r_o + R_C)(R_B + \beta r_e)}$$

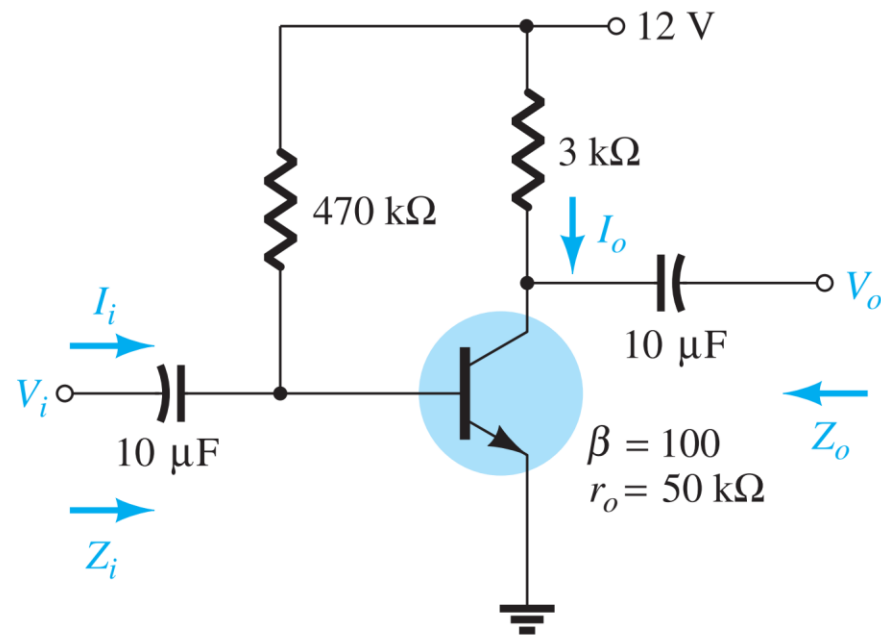
$$A_i \cong \beta \Big|_{r_o \geq 10 R_C, R_B \geq 10 \beta r_e}$$

Current gain from voltage gain:

$$A_i = -A_v \frac{Z_i}{R_C}$$

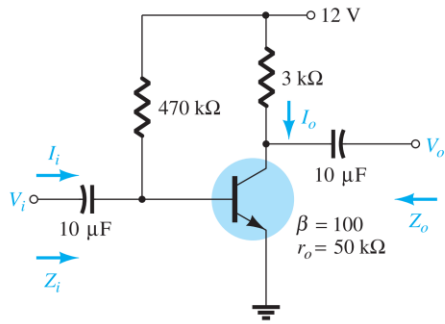
Example

- Determine r_e .
- Find Z_i (with $r_o = \infty \Omega$).
- Calculate Z_o (with $r_o = \infty \Omega$).
- Determine A_v (with $r_o = \infty \Omega$).
- Repeat parts (c) and (d) including $r_o = 50 \text{ k}\Omega$ in all calculations and compare results.



Solution:

a. DC analysis:



$$I_B = \frac{V_{CC} - V_{BE}}{R_B} = \frac{12 \text{ V} - 0.7 \text{ V}}{470 \text{ k}\Omega} = 24.04 \mu\text{A}$$

$$I_E = (\beta + 1)I_B = (101)(24.04 \mu\text{A}) = 2.428 \text{ mA}$$

$$r_e = \frac{26 \text{ mV}}{I_E} = \frac{26 \text{ mV}}{2.428 \text{ mA}} = \mathbf{10.71 \Omega}$$

b. $\beta r_e = (100)(10.71 \Omega) = 1.071 \text{ k}\Omega$

$$Z_i = R_B \parallel \beta r_e = 470 \text{ k}\Omega \parallel 1.071 \text{ k}\Omega = \mathbf{1.07 \text{ k}\Omega}$$

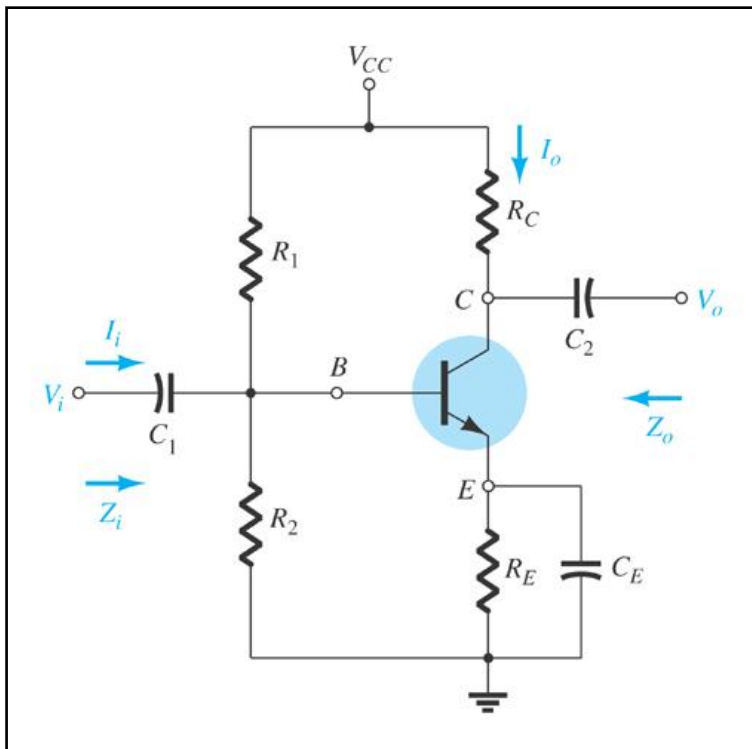
c. $Z_o = R_C = \mathbf{3 \text{ k}\Omega}$

d. $A_v = -\frac{R_C}{r_e} = -\frac{3 \text{ k}\Omega}{10.71 \Omega} = \mathbf{-280.11}$

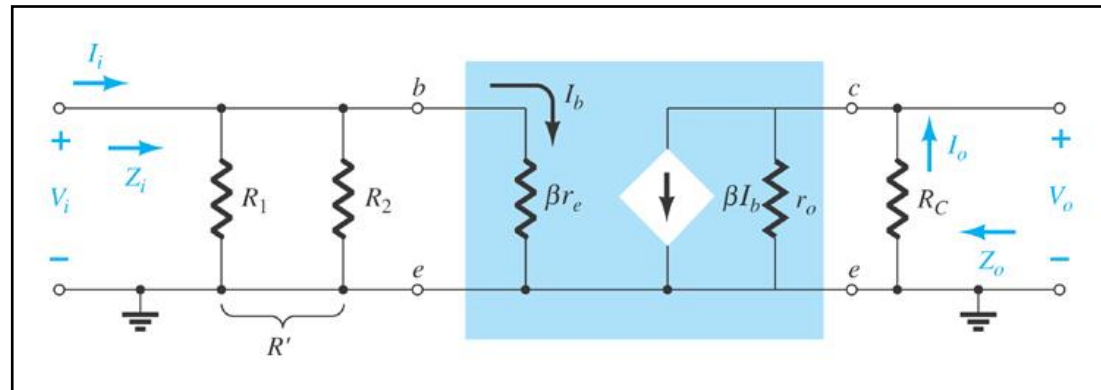
e. $Z_o = r_o \parallel R_C = 50 \text{ k}\Omega \parallel 3 \text{ k}\Omega = \mathbf{2.83 \text{ k}\Omega}$ vs. 3 kΩ

$$A_v = -\frac{r_o \parallel R_C}{r_e} = \frac{2.83 \text{ k}\Omega}{10.71 \Omega} = \mathbf{-264.24}$$
 vs. -280.11

Common-Emitter Voltage-Divider Bias



r_e model requires you to determine β , r_e , and r_o .



Common-Emitter Voltage-Divider Bias Calculations

Input impedance

$$R' = R_1 \parallel R_2$$

$$Z_i = R' \parallel \beta r_e$$

Output impedance

$$Z_o = R_C \parallel r_o$$

$$Z_o \cong R_C \Big|_{r_o \geq 10R_C}$$

Current gain

$$A_i = \frac{I_o}{I_i} = \frac{\beta R' r_o}{(r_o + R_C)(R' + \beta r_e)}$$

$$A_i = \frac{I_o}{I_i} \cong \frac{\beta R'}{R' + \beta r_e} \Big|_{r_o \geq 10R_C}$$

$$A_i = \frac{I_o}{I_i} \cong \beta \Big|_{r_o \geq 10R_C, R' \geq 10\beta r_e}$$

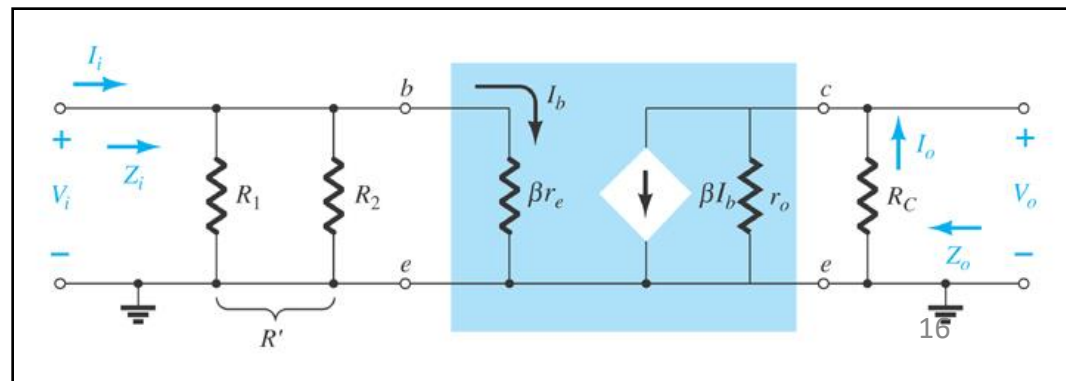
Voltage gain

$$A_v = \frac{V_o}{V_i} = \frac{-R_C \parallel r_o}{r_e}$$

$$A_v = \frac{V_o}{V_i} \cong -\frac{R_C}{r_e} \Big|_{r_o \geq 10R_C}$$

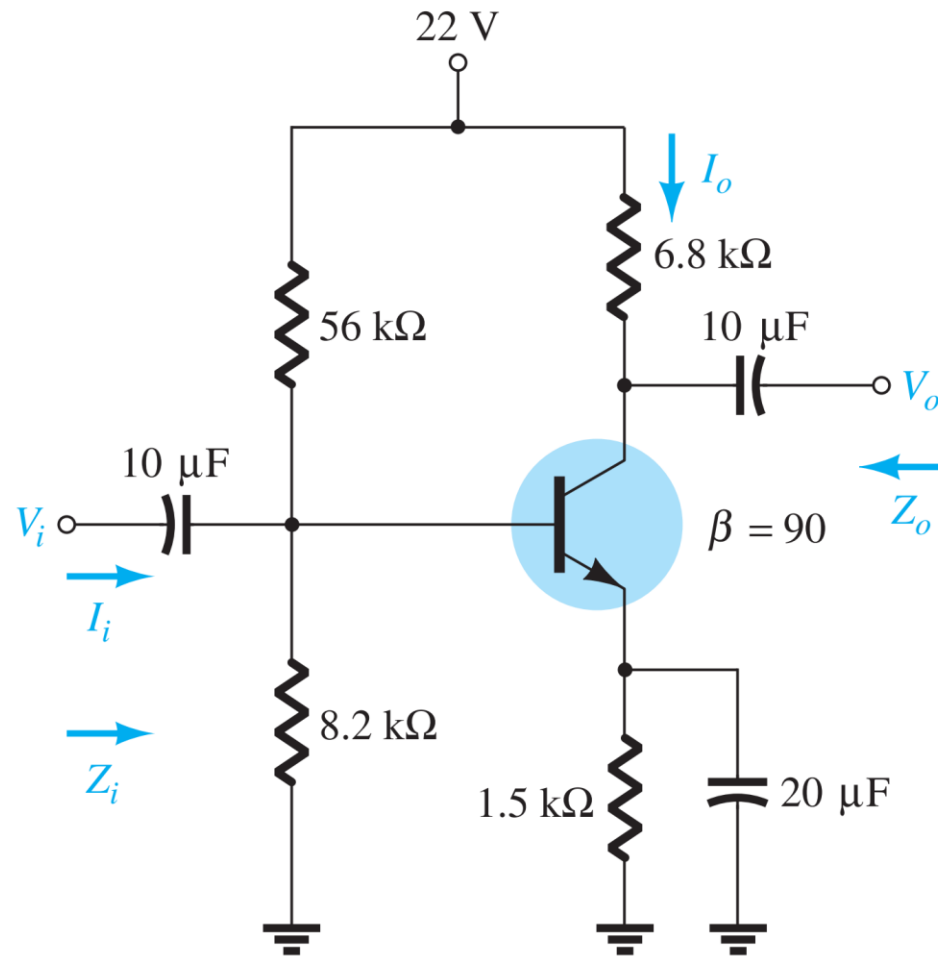
Current gain from A_v

$$A_i = -A_v \frac{Z_i}{R_C}$$



- r_e .
- Z_i .
- Z_o ($r_o = \infty \Omega$).
- A_v ($r_o = \infty \Omega$).
- The parameters of parts (b) through (d) if $r_o = 50 \text{ k}\Omega$ and compare results.

Example



Solution:

a. DC: Testing $\beta R_E > 10R_2$,

$$(90)(1.5 \text{ k}\Omega) > 10(8.2 \text{ k}\Omega)$$

$$135 \text{ k}\Omega > 82 \text{ k}\Omega \text{ (satisfied)}$$

Using the approximate approach, we obtain

$$V_B = \frac{R_2}{R_1 + R_2} V_{CC} = \frac{(8.2 \text{ k}\Omega)(22 \text{ V})}{56 \text{ k}\Omega + 8.2 \text{ k}\Omega} = 2.81 \text{ V}$$

$$V_E = V_B - V_{BE} = 2.81 \text{ V} - 0.7 \text{ V} = 2.11 \text{ V}$$

$$I_E = \frac{V_E}{R_E} = \frac{2.11 \text{ V}}{1.5 \text{ k}\Omega} = 1.41 \text{ mA}$$

$$r_e = \frac{26 \text{ mV}}{I_E} = \frac{26 \text{ mV}}{1.41 \text{ mA}} = \mathbf{18.44 \text{ }\Omega}$$

b. $R' = R_1 \parallel R_2 = (56 \text{ k}\Omega) \parallel (8.2 \text{ k}\Omega) = 7.15 \text{ k}\Omega$

$$Z_i = R' \parallel \beta r_e = 7.15 \text{ k}\Omega \parallel (90)(18.44 \text{ }\Omega) = 7.15 \text{ k}\Omega \parallel 1.66 \text{ k}\Omega = \mathbf{1.35 \text{ k}\Omega}$$

c. $Z_o = R_C = \mathbf{6.8 \text{ k}\Omega}$

d. $A_v = -\frac{R_C}{r_e} = -\frac{6.8 \text{ k}\Omega}{18.44 \text{ }\Omega} = \mathbf{-368.76}$

e. $Z_i = \mathbf{1.35 \text{ k}\Omega}$

$$Z_o = R_C \parallel r_o = 6.8 \text{ k}\Omega \parallel 50 \text{ k}\Omega = \mathbf{5.98 \text{ k}\Omega} \text{ vs. } 6.8 \text{ k}\Omega$$

$$A_v = -\frac{R_C \parallel r_o}{r_e} = -\frac{5.98 \text{ k}\Omega}{18.44 \text{ }\Omega} = \mathbf{-324.3} \text{ vs. } -368.76$$

There was a measurable difference in the results for Z_o and A_v , because the condition $r_o \geq 10R_C$ was *not* satisfied.

